HD74HC132

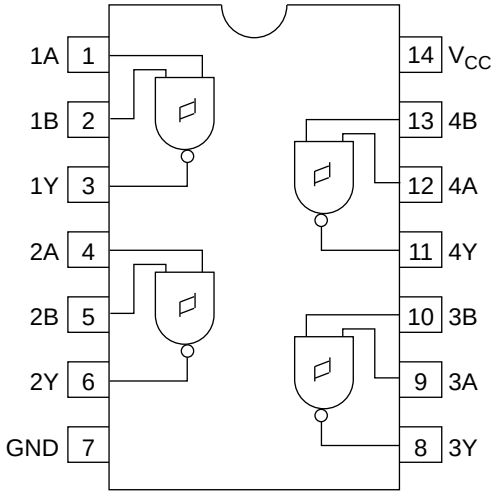
Quad. 2-input NAND Schmitt Triggers

HITACHI

Features

- High Speed Operation: t_{pd} = 9.5 ns typ (C_L = 50 pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: V_{CC} = 2 to 6 V
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 1 µA max (Ta = 25°C)

Pin Arrangement



(Top view)

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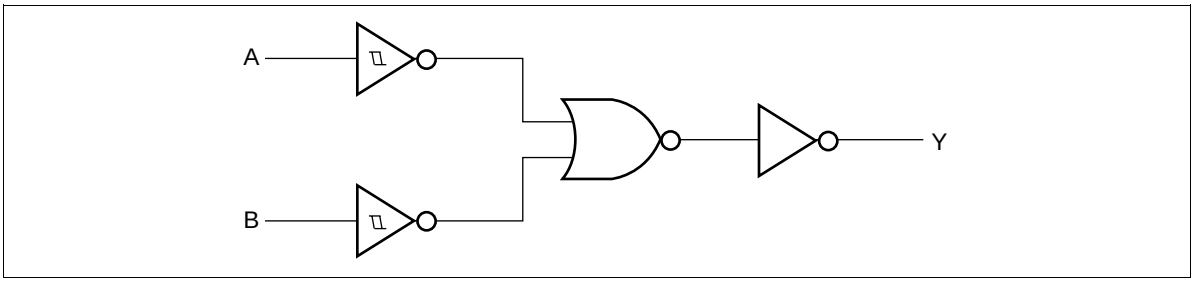
Logic Diagram (1/4)



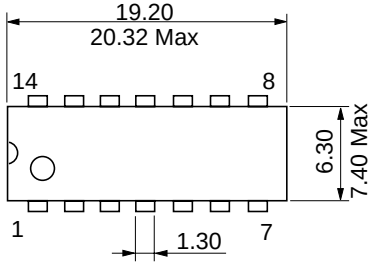
DC Characteristics

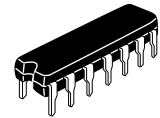
Item	Symbol	V_{CC} (V)	Ta = 25°C Min	Typ	Max	Ta = –40 to +85°C Min	Max	Unit	Test Conditions	
Threshold voltage	V_{T+}	2.0	0.8	—	1.5	0.8	1.5	V		
		4.5	2.25	—	3.15	2.25	3.15			
		6.0	3.0	—	4.2	3.0	4.2			
	V_{T-}	2.0	0.2	—	1.0	0.2	1.0	V		
		4.5	0.9	—	2.25	0.9	2.25			
		6.0	1.2	—	3.0	1.2	3.0			
Hysteresis voltage	V_H	2.0	0.2	—	1.2	0.2	1.2	V		
		4.5	0.4	—	2.25	0.4	2.25			
		6.0	0.6	—	3.0	0.6	3.0			
Output voltage	V_{OH}	2.0	1.9	2.0	—	1.9	—	V	Vin = V_{IH} or V_{IL}	I_{OH} = –20 µA
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	—	—	4.13	—			I_{OH} = –4 mA
		6.0	5.68	—	—	5.63	—			I_{OH} = –5.2 mA
	V_{OL}	2.0	—	0.0	0.1	—	0.1	V	Vin = V_{IH} or V_{IL}	I_{OL} = 20 µA
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			I_{OL} = 4 mA
		6.0	—	—	0.26	—	0.33			I_{OL} = 5.2 mA
Input current	Iin	6.0	—	—	±0.1	—	±1.0	µA	Vin = V_{CC} or GND	
Quiescent supply current	I_{CC}	6.0	—	—	1.0	—	10	µA	Vin = V_{CC} or GND, Iout = 0 µA	

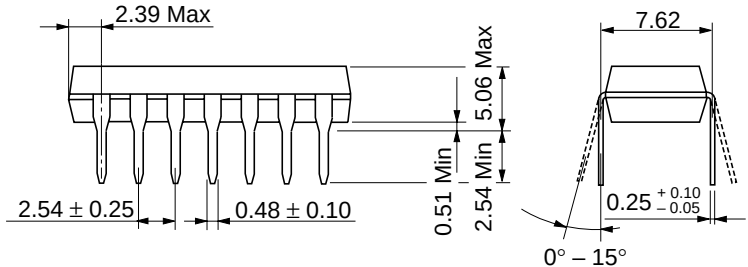
AC Characteristics (C_L = 50 pF, Input t_r = t_f = 6 ns)

			Ta = 25°C			Ta = –40 to +85°C			
Item	**Symbol**	**V_{cc} (V)**	**Min**	**Typ**	**Max**	**Min**	**Max**	**Unit**	**Test Conditions**
Propagation delay time	t_{PLH}	2.0	—	—	100	—	125	ns	
		4.5	—	8	20	—	25		
		6.0	—	—	17	—	21		
	t_{PHL}	2.0	—	—	100	—	125	ns	
		4.5	—	11	20	—	25		
		6.0	—	—	17	—	21		
Output rise/fall time	t_{TLH}	2.0	—	—	75	—	95	ns	
	t_{THL}	4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
Input capacitance	Cin	—	—	5	10	—	10	pF	

Unit: mm

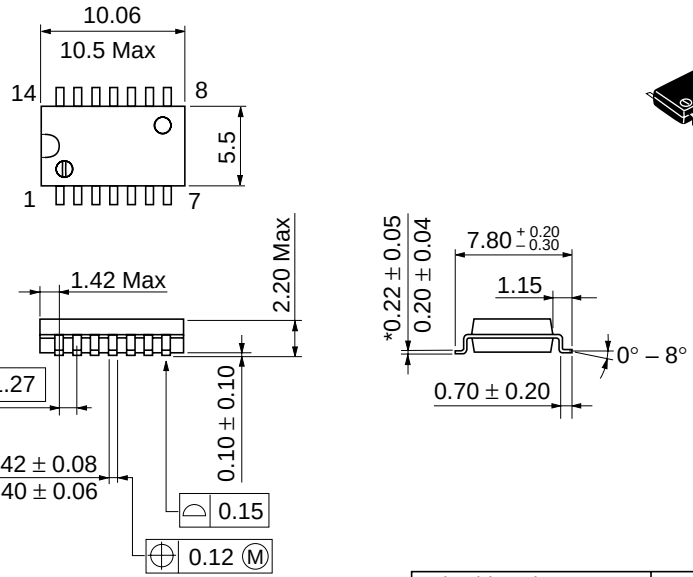


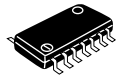




Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

Unit: mm

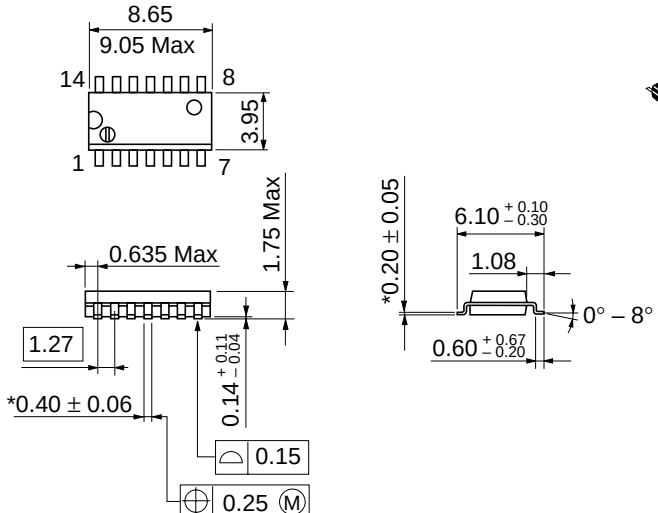




Hitachi Code	FP-14DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.23 g

*Dimension including the plating thickness
Base material dimension

Unit: mm



Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.13 g

*Pd plating

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